

Title (en)
METHOD FOR PRODUCING FUNCTIONAL ELEMENTS FOR CLOCKWORKS AND FUNCTIONAL ELEMENT PRODUCED ACCORDING TO SAID METHOD

Title (de)
VERFAHREN ZUM HERSTELLEN VON FUNKTIONSELEMENTEN FÜR UHRWERKE SOWIE NACH DIESEM VERFAHREN HERGESTELLTES FUNKTIONSELEMENT

Title (fr)
PROCÉDÉ DE FABRICATION D'ÉLÉMENTS FONCTIONNELS POUR DES MOUVEMENTS D'HORLOGERIE ET ÉLÉMENT FONCTIONNEL FABRIQUÉ SELON CE PROCÉDÉ

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Application
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- DE 102007062993 A 20071221
- DE 102008008362 A 20080208
- DE 102008009747 A 20080218
- DE 102008021816 A 20080430
- DE 102008021817 A 20080430
- DE 102008026646 A 20080604
- DE 102008029429 A 20080623

Abstract (en)
[origin: WO2009049591A1] The invention relates to a method for producing springs, particularly spiral springs for oscillating systems of clockworks, particularly clockworks for watches, comprising a spring body having a plurality of turns.

IPC 8 full level
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CPC (source: EP)
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Citation (search report)
See references of WO 2009049591A1

Citation (examination)

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- EP 0732635 A1 19960918 - SUISSE ELECTRONIQUE MICROTECH [CH]
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DE102013114211B3; WO2015087252A1; WO2015011637A2

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